# BTA204X series D, E and F

## **GENERAL DESCRIPTION**

# Passivated guaranteed commutation triacs in a plastic full pack envelope, intended for use in motor control circuits or with other highly inductive loads. These devices balance the requirements of commutation performance and gate sensitivity. The "sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

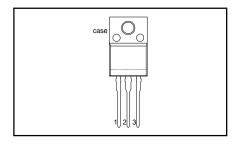
## **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
	BTA204X- BTA204X- BTA204X-	500D 500E 500F	600D 600E 600F	- 800E 800F	
$V_{DRM}$	Repetitive peak	500	600	800	V
I <sub>T(RMS)</sub> I <sub>TSM</sub>	off-state voltages RMS on-state current Non-repetitive peak on-state	4 25	4 25	4 25	A A
	current				

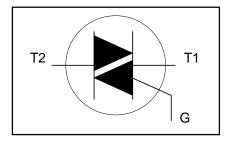
## **PINNING - SOT186A**

PIN	DESCRIPTION			
1	main terminal 1			
2	main terminal 2			
3	gate			
case	isolated			

## PIN CONFIGURATION



## **SYMBOL**



#### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
$V_{DRM}$	Repetitive peak off-state voltages		-	<b>-500</b> 500 <sup>1</sup>	<b>-600</b> 600 <sup>1</sup>	<b>-800</b> 800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>hs</sub> ≤ 92 °C	-		4		Α
I <sub>TSM</sub>	Non-repetitive peak on-state current	full sine wave; $T_j = 25 ^{\circ}\text{C}$ prior to surge t = 20 ms t = 16.7 ms	- -		25 27		A A
l²t dl <sub>⊤</sub> /dt	l²t for fusing Repetitive rate of rise of on-state current after triggering		-		3.1 100		A²s A/μs
$\begin{matrix} I_{GM} \\ V_{GM} \\ P_{GM} \\ P_{G(AV)} \end{matrix}$	Peak gate current Peak gate voltage Peak gate power Average gate power	over any 20 ms period	- - -		2 5 5 0.5		A V W W
$T_{stg} \\ T_{j}$	Storage temperature Operating junction temperature	penou	-40 -		150 125		္င

December 1998 1 Rev 1.000

<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6 A/µs.

BTA204X series D, E and F

# **ISOLATION LIMITING VALUE & CHARACTERISTIC**

 $T_{hs}$  = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>isol</sub>	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65% ; clean and dustfree	ı		2500	>
C <sub>isol</sub>	Capacitance from T2 to external heatsink	f = 1 MHz	ı	10	-	pF

## THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-hs</sub>	Thermal resistance junction to heatsink Thermal resistance	full or half cycle with heatsink compound without heatsink compound in free air		- - 55	5.5 7.2	K/W K/W K/W
I ¹ <b>`</b> th i-a	junction to ambient	in nee an	•	J5	•	17/17

## STATIC CHARACTERISTICS

T<sub>i</sub> = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.		MAX.		UNIT
		BTA204X-			D	Е	F	
I <sub>GT</sub>	Gate trigger current <sup>2</sup>	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$ $T2+ G+$ $T2+ G-$	-	-	5 5	10 10	25 25	mA mA
   I <sub>1</sub>	Latching current	T2- G-   V <sub>D</sub> = 12 V; I <sub>GT</sub> = 0.1 A	-	-	5	10	25	mA
		Ť2+ G+   T2+ G-   T2- G-	- -	- - -	6 9 6	12 18 12	20 30 20	mA mA mA
I <sub>H</sub>	Holding current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$	-	-	6	12	20	mA
$V_{T}$	On-state voltage Gate trigger voltage	$I_T = 5 \text{ A}$ $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$ $V_D = 400 \text{ V}; I_T = 0.1 \text{ A};$	- - 0.25	1.4 0.7 0.4		1.7 1.5 -		V V V
I <sub>D</sub>	Off-state leakage current	$ \begin{aligned} T_j &= 125 \text{ °C} \\ V_D &= V_{DRM(max)}; \\ T_j &= 125 \text{ °C} \end{aligned} $	-	0.1		0.5		mA

December 1998 2 Rev 1.000

<sup>2</sup> Device does not trigger in the T2-, G+ quadrant.

# BTA204X series D, E and F

# **DYNAMIC CHARACTERISTICS**

 $T_j = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.		TYP.	MAX.	UNIT
		BTA204X-	D	Е	F			
dV <sub>D</sub> /dt	Critical rate of rise of off-state voltage	V <sub>DM</sub> = 67% V <sub>DRM(max)</sub> ; T <sub>j</sub> = 125 °C; exponential waveform; gate open circuit	20	30	50	-	-	V/μs
dl <sub>com</sub> /dt	Critical rate of change of commutating current	$V_{DM} = 400 \text{ V}; T_j = 125 ^{\circ}\text{C};$ $I_{T(RMS)} = 4 \text{ A};$ $dV_{com}/dt = 20 \text{V}/\mu\text{s}; gate}$ open circuit	1.0	2.0	2.5	-	-	A/ms
dl <sub>com</sub> /dt	Critical rate of change of commutating current	$V_{DM} = 400 \text{ V}; T_j = 125 ^{\circ}\text{C};$ $I_{T(RMS)} = 4 \text{ A};$ $dV_{com}/dt = 0.1 \text{V}/\mu\text{s}; \text{ gate}$ open circuit	5.0	-	-	-	-	A/ms
t <sub>gt</sub>	Gate controlled turn-on time	$I_{TM} = 12 \text{ A}; V_D = V_{DRM(max)};$ $I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A}/\mu s$	-	-	-	2	ı	μs

# BTA204X series D, E and F

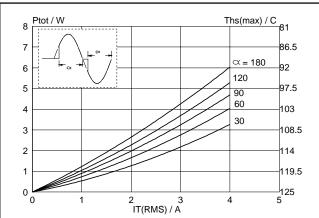


Fig.1. Maximum on-state dissipation,  $P_{tot}$ , versus rms on-state current,  $I_{T(RMS)}$ , where  $\alpha =$  conduction angle.

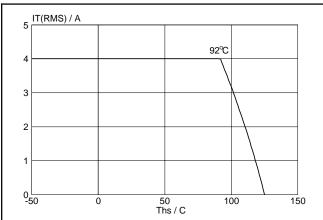


Fig.4. Maximum permissible rms current  $I_{T(RMS)}$ , versus heatsink temperature  $T_{hs}$ .

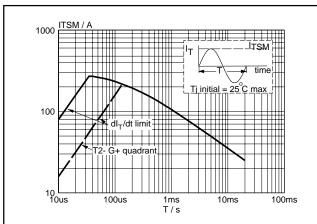


Fig.2. Maximum permissible non-repetitive peak on-state current  $I_{TSM}$ , versus pulse width  $t_p$ , for sinusoidal currents,  $t_p \le 20$ ms.

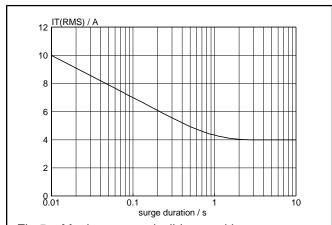


Fig.5. Maximum permissible repetitive rms on-state current  $I_{T(RMS)}$ , versus surge duration, for sinusoidal currents, f = 50 Hz;  $T_{hs} \le 92$ °C.

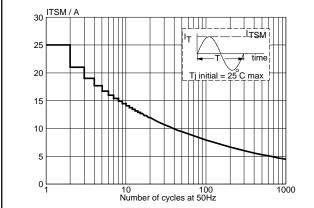


Fig.3. Maximum permissible non-repetitive peak on-state current  $I_{TSM}$ , versus number of cycles, for sinusoidal currents, f = 50 Hz.

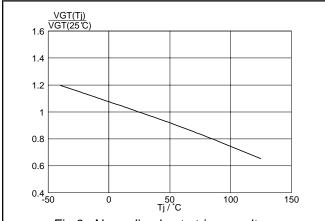
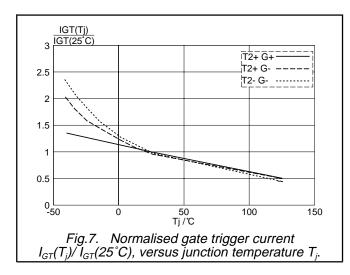
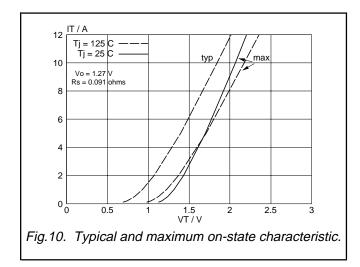
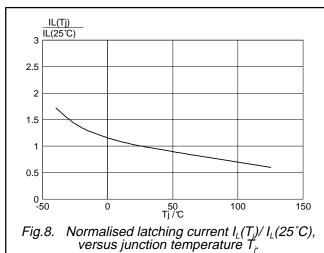


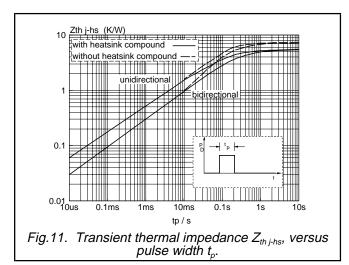
Fig.6. Normalised gate trigger voltage  $V_{GT}(T_j)/V_{GT}(25\,^{\circ}C)$ , versus junction temperature  $T_j$ .

# BTA204X series D, E and F









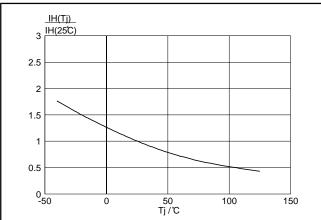
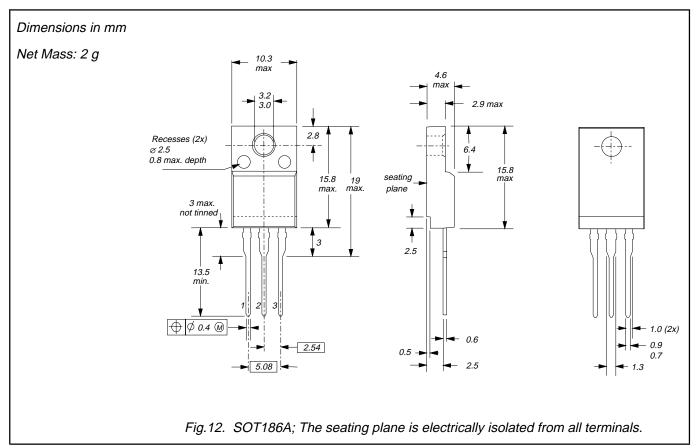


Fig.9. Normalised holding current  $I_H(T_i)/I_H(25^{\circ}C)$ , versus junction temperature  $T_i$ 

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## **MECHANICAL DATA**



- Refer to mounting instructions for F-pack envelopes.
   Epoxy meets UL94 V0 at 1/8".

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## **DEFINITIONS**

Data sheet status							
Objective specification	This data sheet contains target or goal specifications for product development.						
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.						
Product specification	This data sheet contains final product specifications.						

#### Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

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